



## Design Example Report

<b>Title</b>	<b><i>4.8W Charger using LNK520P</i></b>
<b>Specification</b>	Input: 85 – 265 VAC 50/60Hz Output: 12V / 400mA
<b>Application</b>	UPS Battery Charger
<b>Author</b>	Power Integrations Applications Department
<b>Document Number</b>	DER-56
<b>Date</b>	April 20, 2005
<b>Revision</b>	1.0

### Summary and Features

- Low component count battery charger to replace linear transformer and regulator
- Highly efficient operation
- Current limited output
- Optimized switching characteristics minimizes EMI
  - Achieves greater than 8dB $\mu$ V margin to composite conducted limits
  - No Y1 safety capacitor required for EMI compliance
- Small low cost EE16 transformer

The products and applications illustrated herein (including circuits external to the products and transformer construction) may be covered by one or more U.S. and foreign patents or potentially by pending U.S. and foreign patent applications assigned to Power Integrations. A complete list of Power Integrations' patents may be found at [www.powerint.com](http://www.powerint.com).

## Table Of Contents

1	Introduction.....	3
2	Power Supply Specification.....	4
3	Schematic.....	5
4	Circuit Description .....	6
4.1	Input EMI Filtering .....	6
4.2	LinkSwitch Primary and Output Feedback .....	6
4.3	Output Rectification.....	7
4.4	Output Feedback.....	7
5	PCB Layout .....	8
6	Bill Of Materials .....	9
7	Transformer Specification.....	10
7.1	Electrical Diagram .....	10
7.2	Electrical Specifications.....	10
7.3	Materials.....	10
7.4	Transformer Build Diagram .....	11
7.5	Transformer Construction.....	11
8	Transformer Spreadsheet.....	12
9	Performance Data .....	14
9.1	Efficiency at Full Load (400mA) .....	14
9.2	Efficiency vs. Output Current.....	15
9.3	Efficiency and Input Power Comparison to Transformer + LDO.....	16
9.4	No-load Input Power.....	17
9.5	Regulation .....	18
9.5.1	Load and Line .....	18
9.5.2	Battery Load Charge Profile at 120VAC Input.....	18
10	Waveforms.....	19
10.1	Drain Voltage and Current, Normal Operation .....	19
10.2	Output Voltage Start-up Profile .....	19
10.3	Output Ripple Measurements.....	20
10.3.1	Ripple Measurement Technique .....	20
10.3.2	Measurement Results .....	21
11	Conducted EMI .....	22
12	Revision History.....	23

### Important Note:

Although this board is designed to satisfy safety isolation requirements, the engineering prototype has not been agency approved. Therefore, all testing should be performed using an isolation transformer to provide the AC input to the prototype board.

Design Reports contain a power supply design specification, schematic, bill of materials, and transformer documentation. Performance data and typical operation characteristics are included. Typically only a single prototype has been built.



## 1 Introduction

This document is an engineering prototype report describing a +12V 400mA charger power supply. The power supply utilizes the LinkSwitch LNK520 device. The LinkSwitch integrates a 700V MOSFET, PWM controller, high-voltage start-up, thermal shutdown, and fault protection circuitry. This power supply is a cost effective replacement of linear transformer based power supplies with the additional features of universal input voltage range and high-energy efficiency.

The document contains the power supply specification, schematic, bill of materials, transformer documentation, printed circuit layout, and performance data.



**Figure 1** – Populated Circuit Board Photograph

## 2 Power Supply Specification

Description	Symbol	Min	Typ	Max	Units	Comment
<b>Input</b>						
Voltage	$V_{IN}$	85		265	VAC	2 Wire – no P.E.
Frequency	$f_{LINE}$	47	50/60	64	Hz	
No-load Input Power (230 VAC)				0.6	W	
<b>Output</b>						
Output Voltage 1	$V_{OUT1}$		12		V	± 5% 20 MHz bandwidth
Output Ripple Voltage 1	$V_{RIPPLE1}$				mV	
Output Current 1	$I_{OUT1}$		400		mA	
<b>Total Output Power</b>						
Continuous Output Power	$P_{OUT}$			4.8	W	
Peak Output Power	$P_{OUT\_PEAK}$			4.8	W	
<b>Efficiency</b>	$\eta$	75			%	Measured at $P_{OUT}$ (4.8 W), 25 °C
<b>Environmental</b>						
Conducted EMI			Meets CISPR22B / EN55022B			1.2/50 $\mu$ s surge, IEC 1000-4-5, Series Impedance: Differential Mode: 2 $\Omega$ Common Mode: 12 $\Omega$
Safety			Designed to meet IEC950, UL1950 Class II			
Surge			TBD		kV	
Surge			TBD		kV	100 kHz ring wave, 500 A short circuit current, differential and common mode
Ambient Temperature	$T_{AMB}$	0		50	°C	Free convection, sea level



### 3 Schematic

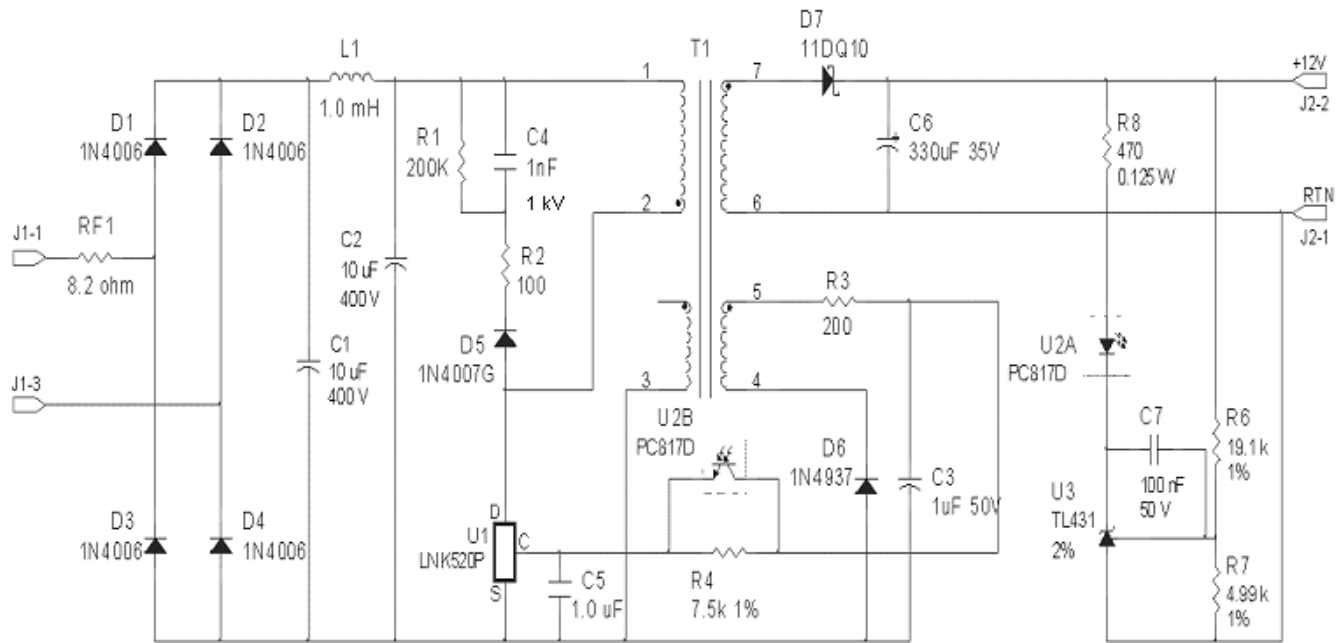


Figure 2 – Schematic



## 4 Circuit Description

The circuit schematic shown in Figure 2 shows a design that provides a constant voltage / constant current (CV/CC) output characteristic from a universal input voltage range of 85 VAC-265 VAC. This design delivers 4.8 W with nominal peak power point voltage of 12 V and a current of 400mA.

### 4.1 Input EMI Filtering

The bridge rectifier, D1-D4, rectifies the AC input and is smoothed by C1 and C2, with inductor L1 forming a  $\pi$ -filter to attenuate differential mode conducted EMI. Resistor RF1 is a fusible, flameproof type, providing protection from primary-side short circuits and line surges and provides additional differential EMI filtering. The switching frequency of 42kHz allows a simple EMI filter to be used without the need for a Y capacitor while still meeting international EMI standards.

Capacitors C1 and C2 are sized to maintain a minimum DC voltage of around 127 V at the minimum AC input voltage. Their ESR should also be as low as possible to reduce differential mode EMI generation. The value of L1 is selected to give acceptable differential mode EMI attenuation with a current rating to meet the RMS input current at low line (or acceptable temperature rise). Conducted emissions in this design are compliant with EN55022B / CISPR 22B and FCC B limits with no input Y1 safety capacitor.

### 4.2 LinkSwitch Primary and Output Feedback

The LNK520P contains the necessary functions to implement start-up and auto-restart (output protection) operation, output constant voltage (CV) and constant-current (CC) control.

When power is applied, high voltage DC appears at the DRAIN pin of *LinkSwitch* (U1). The CONTROL pin capacitor C5 is then charged through a switched high voltage current source connected internally between the DRAIN and CONTROL pins. When the CONTROL pin reaches approximately 5.6 V relative to the SOURCE pin, the internal current source is turned off. The internal control circuitry is activated and the high voltage MOSFET starts to switch, using the energy in C5 to power the IC.

Diode D6 rectifies the output of the bias winding, which is then smoothed by C3 to provide a DC voltage to be fed to the CONTROL pin via R4. Resistor R3 is added to filter noise due to leakage inductance. The value of R4 is set such that, at the peak power point, where the output is still in CV regulation, the CONTROL pin current is approximately 2.2mA.

As the output load is increased, the peak power point (defined by  $0.5 \times L \times I^2 \times f$ ) is exceeded. The output voltage and therefore primary side bias voltage reduce. The reduction in the bias voltage results in a proportional reduction of CONTROL pin current, which lowers the internal *LinkSwitch* current limit (current limit control).



Constant current (CC) operation controls secondary-side output current by reducing the primary-side current limit. The current limit reduction characteristic has been optimized to maintain an approximate constant output current as the output voltage and bias voltage is reduced.

If the load is increased further and the CONTROL pin current falls below approximately 0.8mA, the CONTROL pin capacitor C5 will discharge and *LinkSwitch* will enter auto-restart operation.

Current limit control removes the need for any secondary-side current sensing components. Removing the secondary sense circuit dramatically improves efficiency, giving the associated benefit of reduced enclosure size.

Diode D5, C4, R1, and R2 form the primary clamp network. This limits the peak DRAIN voltage due to leakage inductance. Resistor R2 allows the use of a slow, low cost rectifier diode by limiting the reverse current through D5 when U1 turns on. The selection of a slow diode improves radiated EMI and also improves CV regulation, especially at no load. A glass passivated diode should be used with specified recovery time.

#### **4.3 Output Rectification**

Output rectification is provided by Schottky diode D7. The low forward voltage provides high efficiency across the operating range. Low ESR capacitor C6 achieves minimum output ripple and maximizes operating efficiency.

#### **4.4 Output Feedback**

Resistors R6 and R7 divide down the supply output voltage and apply it to the reference pin of error amplifier U3. Shunt regulator U3 drives Optocoupler U2 through resistor R8 to provide feedback information to the U1 CONTROL pin. Capacitor C7 rolls off the gain of U3 and is sufficient to compensate the control loop of the power supply.



## 5 PCB Layout

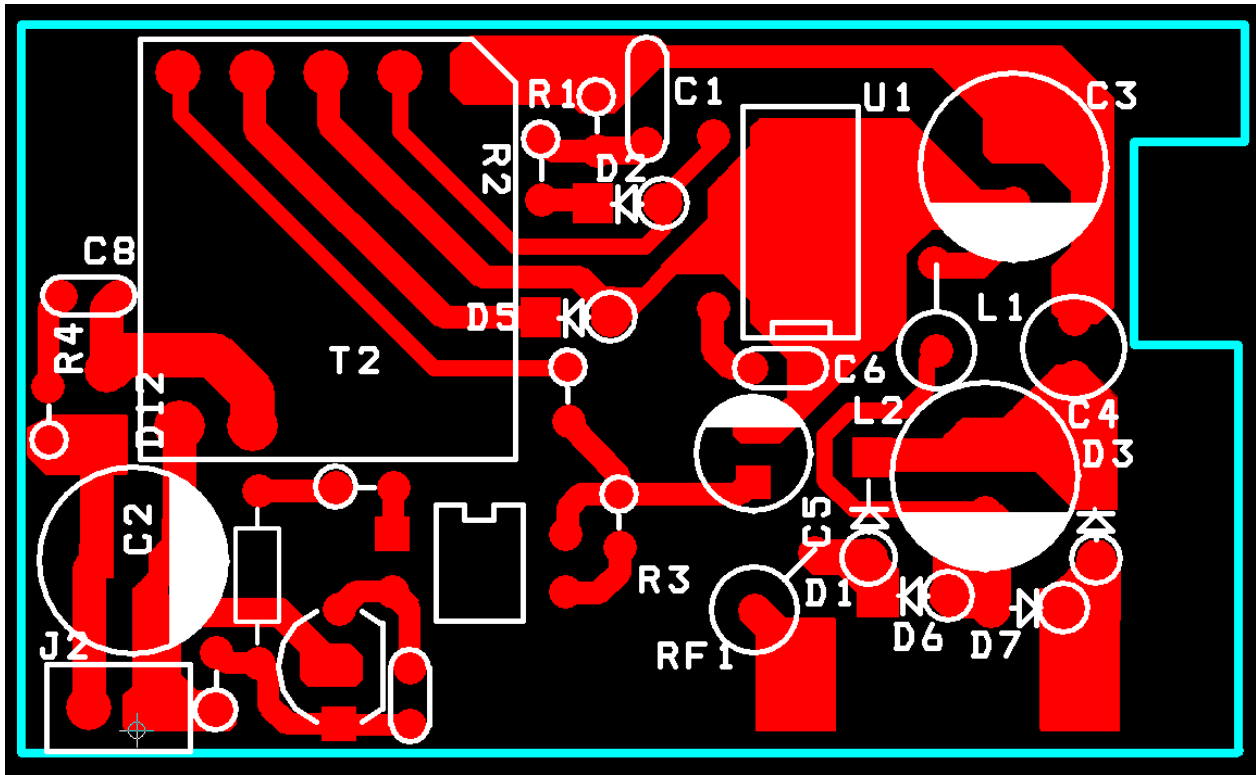


Figure 3 – Printed Circuit Layout



## 6 Bill Of Materials

<i>Item</i>	<i>QTY</i>	<i>Ref</i>	<i>Des</i>	<i>Description</i>	<i>Manufacturer</i>	<i>Mfg Part Number</i>
1	2	C1 C2		10uF, 400 V, Electrolytic, Low ESR, 2.9 Ohms, (10 x 20)	UCC	KMX400VB10RM10X20LL
2	1	C3		1uF, 50 V, Electrolytic, Gen. Purpose, (5 x 11)	UCC	KMG50VB1R0M5X11LL
3	1	C4		1nF, 1 kV, Disc Ceramic	Panasonic	ECK-D3A102KBP
4	1	C5		1.0uF, 50 V, Ceramic, X7R	Panasonic	ECU-S1H105KBB
5	1	C6		330uF, 35 V, Electrolytic, Very Low ESR, 38mOhm, (10 x 16)	UCC	KZE35VB331MJ16LL
6	1	C7		100nF, 50 V, Ceramic, X7R	Panasonic	ECU-S1H104KBB
7	4	D1 D2 D3 D4		800 V, 1 A, Rectifier, DO-41		1N4006
8	1	D5		1000 V, 1 A, Rectifier, Glass Passivated, 2 us, DO-41		1N4007GP
9	1	D6		600 V, 1 A, Fast Recovery Diode, 200 ns, DO-41		1N4937
10	1	D7		100 V, 1.1 A, Schottky, DO-41		11DQ10
11	1	L1		1mH, 0.15 A, Ferrite Core	Token	SBCP-47HY102B
12	1	R1		200 k, 5%, 1/2 W, Carbon Film		CFR-50JB-200K
13	1	R2		100 R, 5%, 1/8 W, Carbon Film		CFR-12JB-91R
14	1	R3		200 R, 5%, 1/4 W, Carbon Film		CFR-25JB-200R
15	1	R4		7.5 k, 1%, 1/4 W, Metal Film		MFR-25FBF-7K50
16	1	R6		19.1 k, 1%, 1/4 W, Metal Film		MFR-25FBF-19K1
17	1	R7		4.99 k, 1%, 1/4 W, Metal Film		MFR-25FBF-4K99
18	1	R8		470 R, 5%, 1/8 W, Carbon Film		CFR-12JB-470R
19	1	RF1		8.2 R, 2.5 W, Fusible/Flame Proof Wire Wound		CRF253-4 5T 8R2
20	1	T1		EE16 Flyback Transformer		
21	1	U1		LinkSwitch, LNK520P, DIP-8B	Power Integrations	LNK520P
22	1	U2		Opto coupler, 35 V, CTR 300-600%, 4-DIP	Isocom, Sharp	ISP817D, PC817X4
23	1	U3		2.495 V Shunt Regulator IC, 2%, 0 to 70C, TO-92	TI	TL431CLP



## 7 Transformer Specification

### 7.1 Electrical Diagram

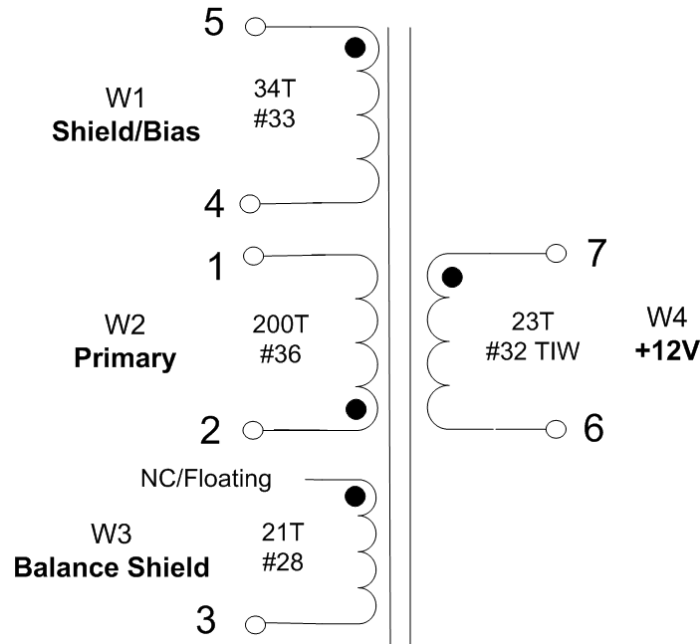


Figure 4 – Transformer Electrical Diagram

### 7.2 Electrical Specifications

<b>Electrical Strength</b>	1 second, 60 Hz, from Pins 1-5 to Pins 6-7	3000 VAC
<b>Primary Inductance</b>	Pins 1-2, all other windings open, measured at 100 kHz, 0.4 VRMS	5000 $\mu$ H, -10/+10%
<b>Resonant Frequency</b>	Pins 1-2, all other windings open	500 kHz (Min.)
<b>Primary Leakage Inductance</b>	Pins 1-2, with Pins 6-7 shorted, measured at 100 kHz, 0.4 VRMS	250 $\mu$ H (Max.)

### 7.3 Materials

Item	Description
[1]	Core: EE16, PC40EE16 TDK – $Al = 124nH/T^2$
[2]	Bobbin: Horizontal 10 pin
[3]	Magnet Wire: #33 AWG
[4]	Magnet Wire: #36 AWG
[5]	Magnet Wire: #28 AWG
[6]	Triple Insulated Wire: #32 AWG
[7]	Tape: 3M 1298 Polyester Film (white) 2.2mils thick
[8]	Varnish

## 7.4 Transformer Build Diagram

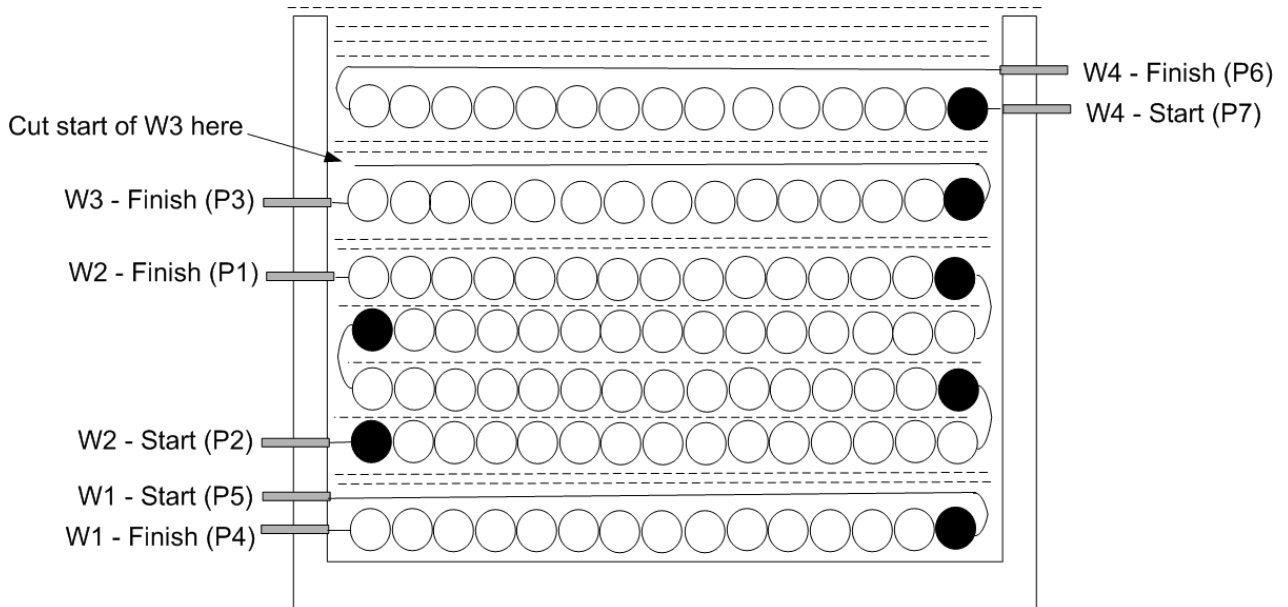


Figure 5 – Transformer Build Diagram

## 7.5 Transformer Construction

<b>Bobbin Preparation</b>	Pull pins 8-10 on bobbin [2] to provide polarization. Align bobbin on mandrill with pins 1-5 on right hand side.
<b>Core Cancel/Bias</b>	Starting on left hand side of bobbin, wind 34 turns of item [3] uniformly on a single layer from left to right. Finish winding on pin 4. Wrap start of wire to pin 5.
<b>Basic Insulation</b>	Use two layers of item [7] for basic insulation.
<b>Primary</b>	Start at Pin 2. Wind 50 turns of item [4] uniformly on a single layer from right to left. Apply one layer of tape, wind 50 turns on the secondary, third and fourth layer (200T total) adding 1 layer of tape [7] between each layers. Finish winding on pin 1.
<b>Basic Insulation</b>	Use two layers of item [7] for basic insulation.
<b>Balance Shield</b>	Starting on left hand side of bobbin, wind 21 turns of item [5] uniformly on a single layer from left to right. Finish winding on pin 3. Wrap start of wire to right hand side of bobbin and cut close to start of winding leaving it unconnected (as shown in Figure 5).
<b>Basic Insulation</b>	Use two layers of item [7] for basic insulation.
<b>Secondary Winding</b>	Start at Pin 7. Wind 23 of item [6] uniformly on a single layer from left to right. Finish on Pins 6.
<b>Outer Wrap</b>	Wrap windings with 3 layers of tape (item [7]).
<b>Final Assembly</b>	Assemble and secure core halves. Varnish impregnate (item [8]).

## 8 Transformer Spreadsheet

A	B	D	F	G	I
LinkSwitch (LNK52X) 032204; Rev.1.8; Copyright Power Integrations 2004	INPUT	INFO	OUTPUT	UNIT	LinkSwitch (LNK52X) 032204 Rev.1.8; Copyright Power Integrations 2004
<b>ENTER APPLICATION VARIABLES</b>					<b>APC 13.7V/400mA Charger</b>
VACMIN	108			Volts	Minimum AC Input Voltage
VACMAX	265			Volts	Maximum AC Input Voltage
fL	50			Hertz	AC Mains Frequency
VO	13.7			Volts	Output Voltage
IO	0.4			Amps	Continuous Nominal Output current
VBIAS	20				Bias voltage (recommended default 20V, minimum 16V)
IC	3			msec	Bridge Rectifier Conduction Time Estimate
CIN	16.8			uFarads	Input Filter Capacitor
<b>ESTIMATED LOSSES</b>					
PCORE			266.4	mW	Estimated Core Losses at peak Flux Density (BP)
RCLAMP			200.0	Kohm	Primary clamp resistor (recommended default clamp resistor, RCLAMP)
ESR			0.150	Ohms	Output Capacitor ESR
RSEC			0.2	Ohms	Estimated Resistance of transformer secondary winding.
<b>DC INPUT VOLTAGE PARAMETERS</b>					
VMIN			133	Volts	Minimum DC Input Voltage
VMAX			375	Volts	Maximum DC Input Voltage
<b>ENTER OUTPUT CABLE PARAMETERS</b>					
RCABLE			0.3	Ohms	Resistance of total length of cable from power supply terminals to load and back.
VCABLE			0.120	Volts	Drop along cable connecting power supply to load
<b>ENTER LinkSwitch &amp; OUTPUT DIODE VARIABLES</b>					
LinkSwitch	LNK520			Universal	115 Doubled/230
			Power	5.5	3.5
I <sup>2</sup> f			2710	A <sup>2</sup> Hz	I <sup>2</sup> f (typical) co-efficient for LinkSwitch
VOR	130		130.00	Volts	Reflected Output Voltage (40<VOR<80 recommended)
VLEAK			2.00	Volts	Error in Feedback voltage as a result of leakage inductance in primary circuit.
VD			1.1	Volts	diode)
VR			100	Volts	Rated Peak Rep Reverse Voltage of secondary diode
ID	3			Amps	Rated Average Forward current for secondary diode
<b>DISCONTINUOUS MODE CHECK</b>					
KDP			1.42		Ensure KDP > 1.15 for discontinuous mode operation.
TON			9.96	us	Linkswitch conduction time
TDON			9.74	us	Secondary Diode conduction time
<b>VOLTAGE STRESS ON LinkSWITCH AND OUTPUT DIODE</b>					
VDRAIN			668	Volts	Maximum Drain Voltage Estimate (includes Effect of Leakage Inductance)
PIVS			56.7	Volts	Output Rectifier Maximum Reverse Voltage
<b>CURRENT WAVEFORM SHAPE PARAMETERS</b>					
DMAX			0.42		Maximum Operating Duty Cycle
I <sub>AVG</sub>			0.053	Amps	Average Primary Current
I <sub>RMS</sub>			0.095	Amps	Primary RMS Current
<b>ENTER TRANSFORMER CORE/CONSTRUCTION VARIABLES</b>					
Core Type	ee16				
Core		PC40EE16-Z			
Bobbin		BE-16-116CP			
AE			0.192	cm <sup>2</sup>	Core Effective Cross Sectional Area
LE			3.5	cm	Core Effective Path Length
AL			1140	nH/T <sup>2</sup>	Ungapped Core Effective Inductance
VE			795	mm <sup>3</sup>	Effective Core Volume
BW			8.5	mm	Bobbin Physical Winding Width
KCORE			588	kW/m <sup>3</sup>	Core losses per unit volume
T(n)	0.9572		0.9572		Estimated transformer efficiency. T(n)=(PSCU+PCORE/2)/POEFF. Re-iterate with n = 0.9572
M			0	mm	Safety Margin Width
NS	23				Number of Secondary Turns
<b>TRANSFORMER PRIMARY DESIGN PARAMETERS</b>					
dLP			1.003		Constant to account for reduction of inductance at higher flux densities. (0.999<dLP<1.05)
LP			4987	uHenries	Primary Inductance
L	4		4		Number of Primary Layers
LBIAS	0.9		0.9		Number of Bias winding Layers
NP			200		Primary Winding Number of Turns
NB			28		
ALG			124	nH/T <sup>2</sup>	Gapped Core Effective Inductance
BP			3629	Gauss	Peak Flux Density (BP<3700)
LG			0.17	mm	Core Gap Length for primary inductance
OD			0.17	mm	Maximum Primary Wire Diameter including insulation to give specified number of layers.
DIA			0.13	mm	Bare conductor diameter
AWG			36	AWG	Primary Wire Gauge (Rounded to next smaller standard AWG value)
CMA			268	Cmil/Amp	Primary Winding Current Capacity (200 < CMA < 500)
AWG BIAS			30	AWG	



A	B	D	F	G	I
<b>TRANSFORMER SECONDARY DESIGN PARAMETERS</b>					
ISP			2.21	Amps	Peak Secondary Current
ISRMS			0.82	Amps	Secondary RMS Current
IRIPPLE			0.71	Amps	Output Capacitor RMS Ripple Current
AWGS			31	AWG	Secondary Wire Gauge (Rounded up to next larger standard AWG value)
DIAS			0.23	mm	Secondary Minimum Bare Conductor Diameter
ODS			0.37	mm	Secondary Maximum Insulated Wire Outside Diameter
INSS			0.07	mm	Maximum Secondary Insulation Wall Thickness
VSEC			0.080	Volts	Voltage Drop across secondary winding
<b>FEEDBACK CIRCUIT COMPONENTS</b>					
RFB			7.07	k-Ohms	Feedback resistor
PRFB			37	mW	Losses in the Feedback resistor
<b>ESTIMATED LOSSES IN POWER SUPPLY AND EFFICIENCY, LOW LINE</b>					
PCABLE			48	mW	Power loss in Output Cable
PSCU			134	mW	Transformer Secondary Copper Losses
PDIODE			440	mW	Output Diode conduction loss
PCAP			100	mW	
PBIAS			51	mW	Power Loss in Feedback circuit
PCONDUCTION			378	mW	Conduction Losses in LinkSwitch calculated at 100C
PCLAMP			85	mW	Primary clamp losses
PCORE			266	mW	Core Losses at peak Flux Density
PBRIDGE			54	mW	Primary bridge rectifier losses
EFFICIENCY ESTIMATE			77.9	%	Estimated Power Supply Efficiency
<b>ADDITIONAL OUTPUT</b>					
VX				Volts	Auxiliary Output Voltage
VDX				Volts	Auxiliary Diode Forward Voltage Drop
NX			0.00		Auxiliary Number of Turns
PIVX			0.00	Volts	Auxiliary Rectifier Maximum Peak Inverse Voltage



## 9 Performance Data

All measurements performed at room temperature, 60 Hz input frequency.

### 9.1 Efficiency at Full Load (400mA)

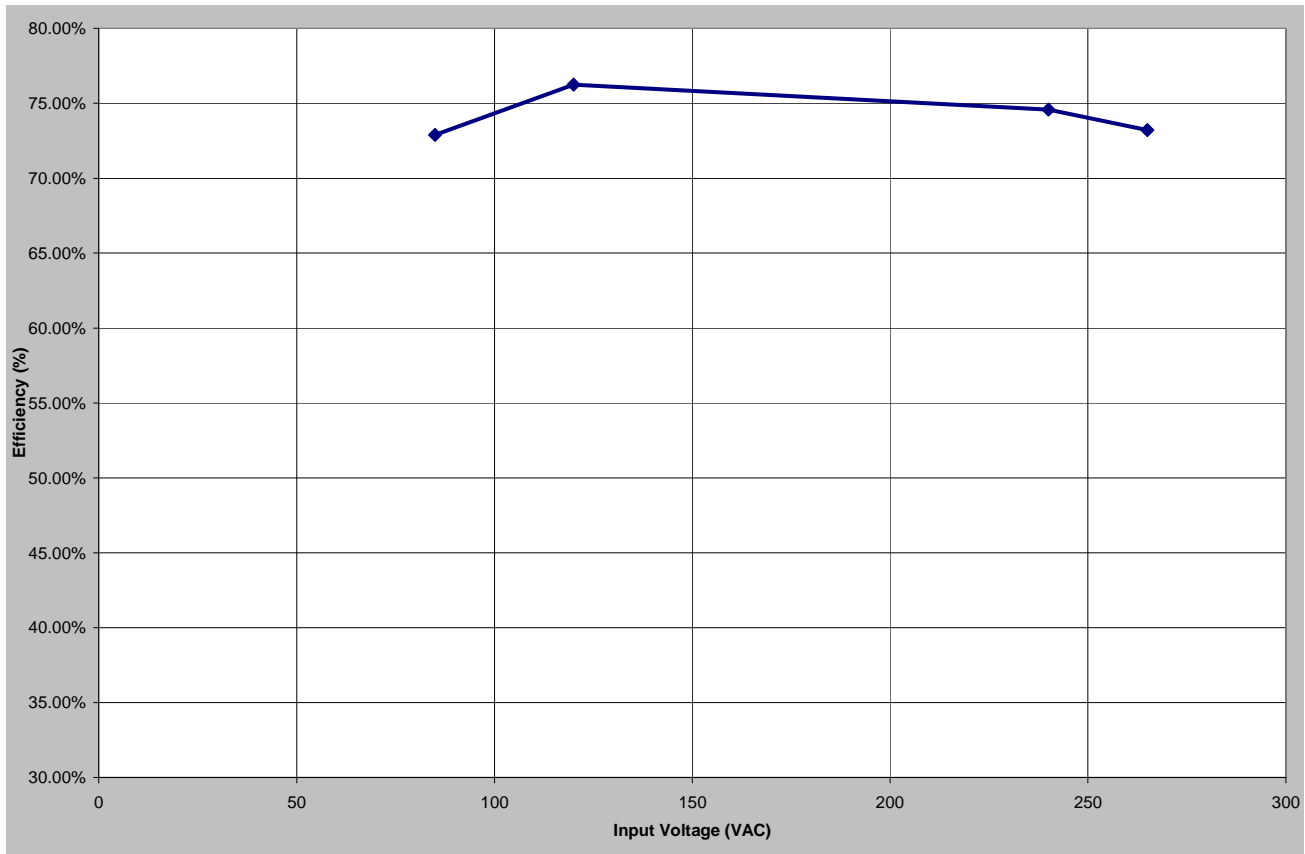


Figure 6 – Efficiency vs. Input Voltage, Room Temperature



### 9.2 Efficiency vs. Output Current

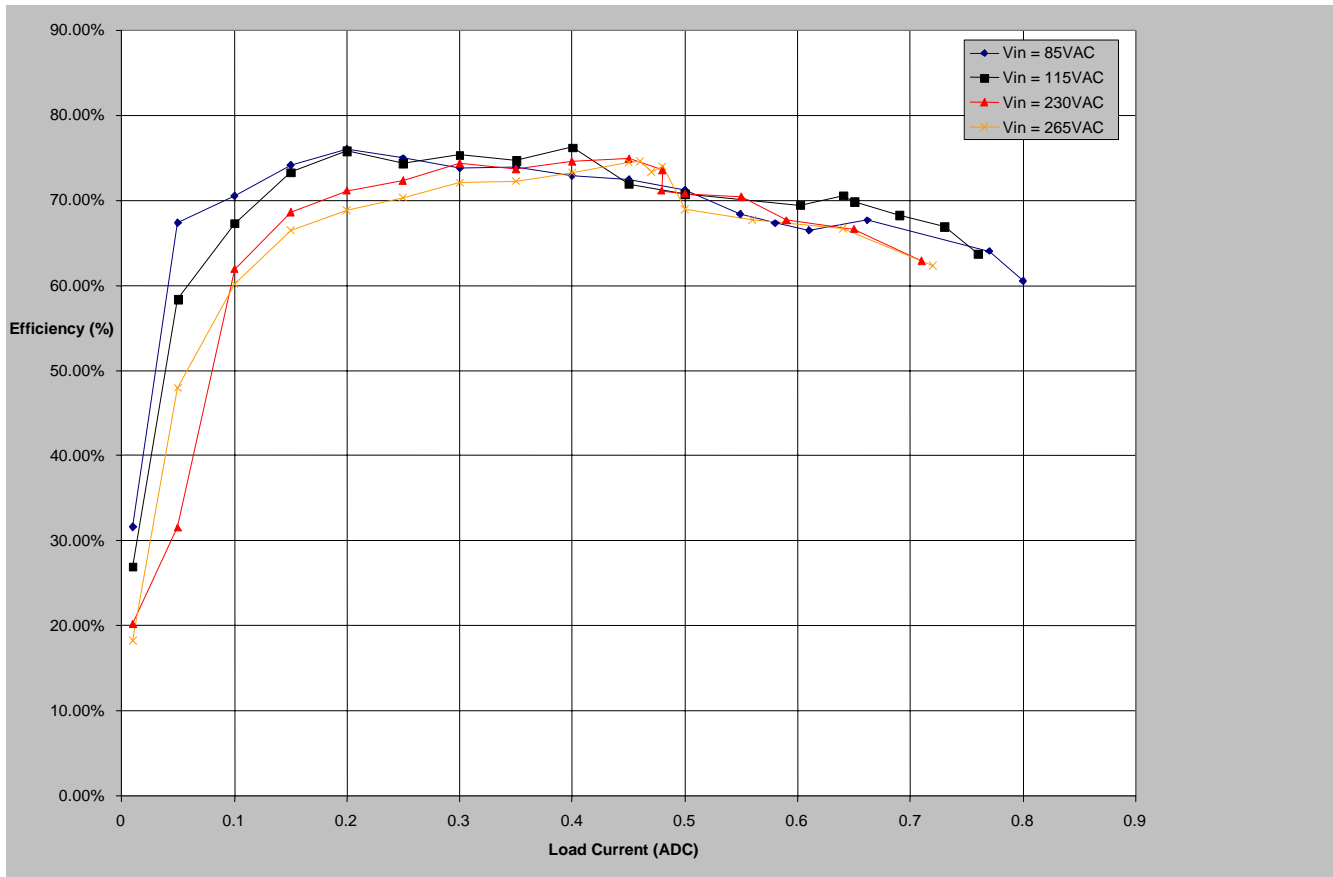


Figure 7 – Efficiency vs. Output Load, Room Temperature



### 9.3 Efficiency and Input Power Comparison to Transformer + LDO

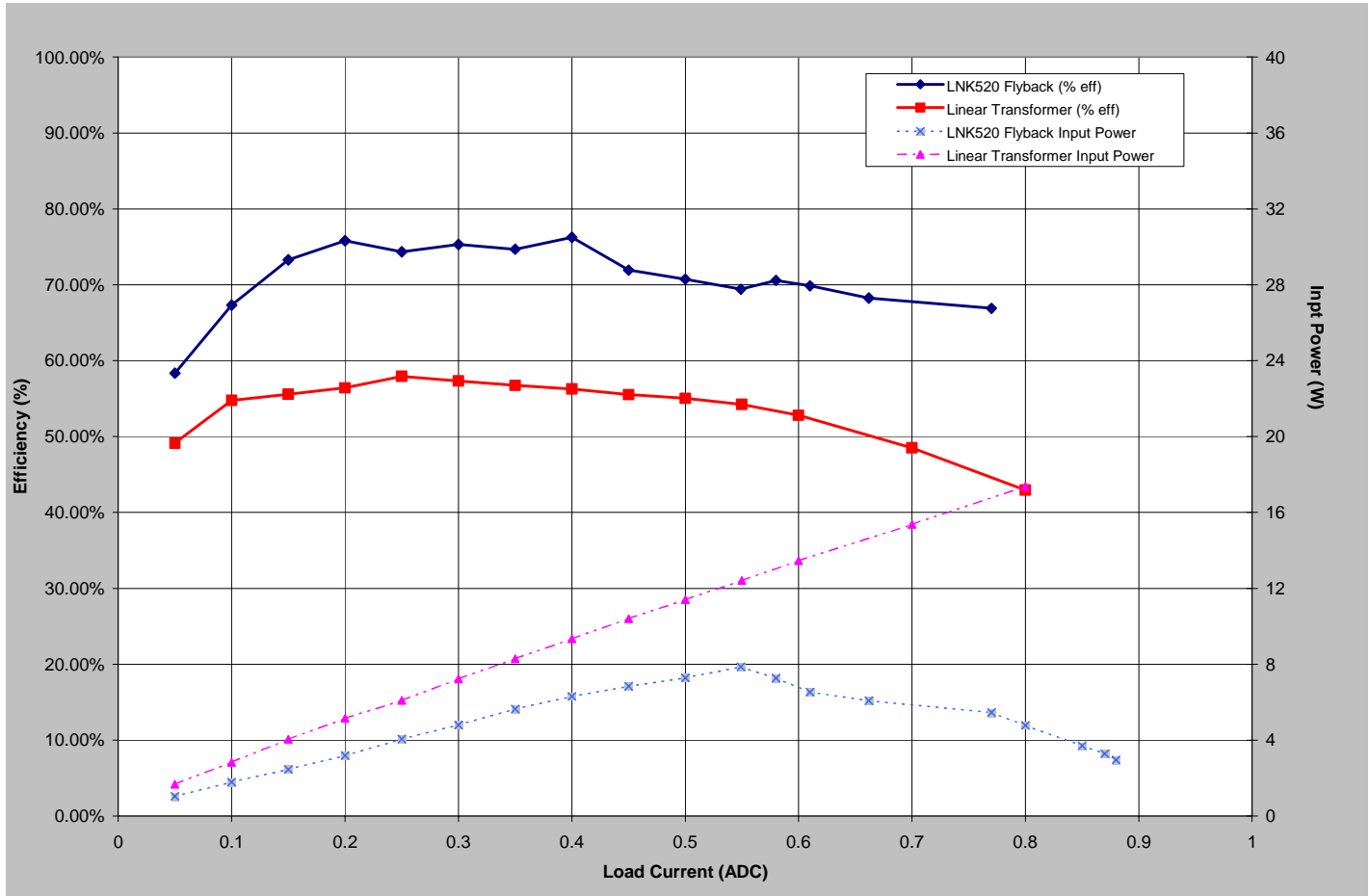
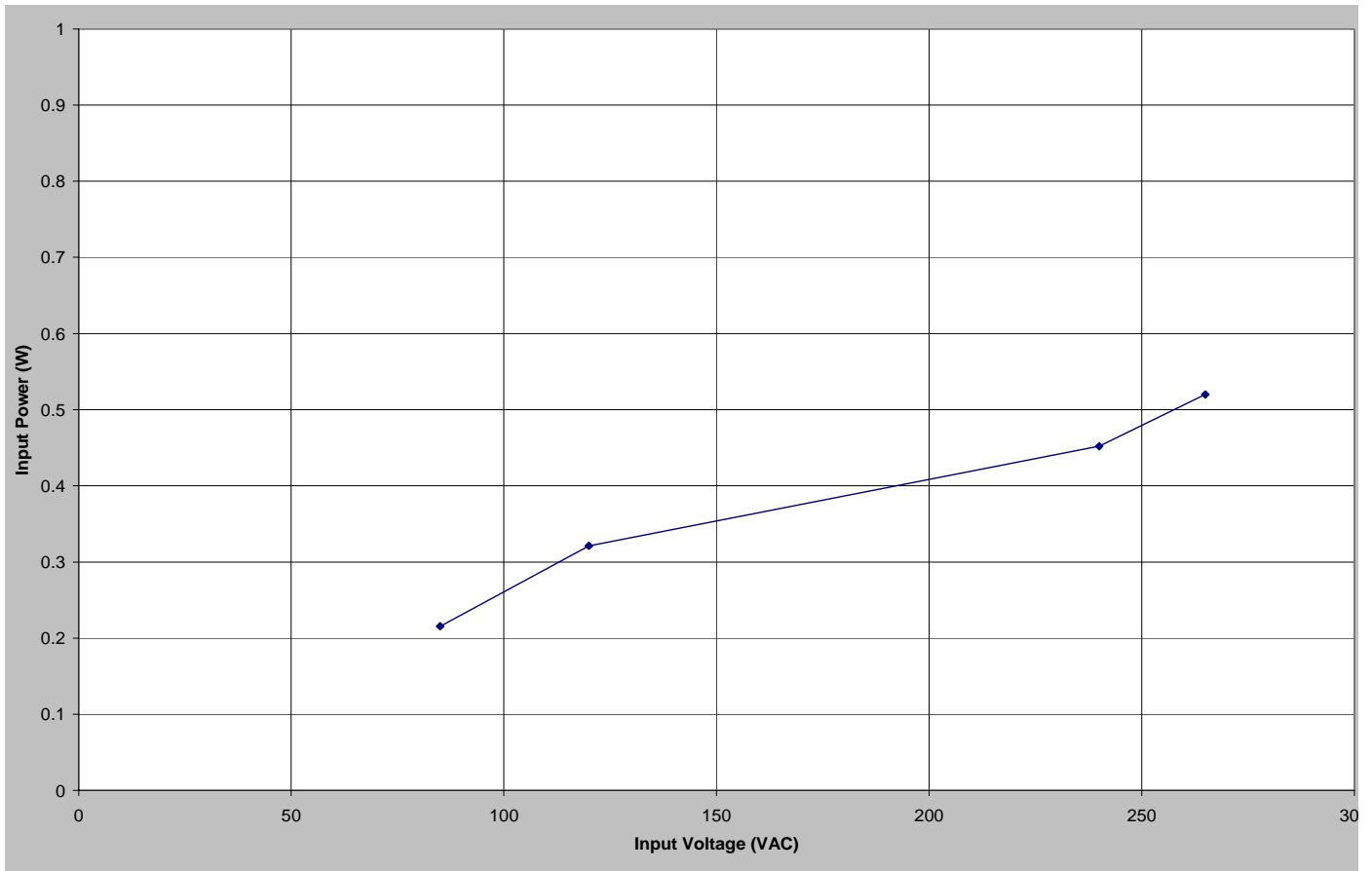


Figure 8 – Efficiency and Input Power at 120VAC Input, Room Temperature, 60 Hz.





**9.4 No-load Input Power**



**Figure 9** – Zero Load Input Power vs. Input Line Voltage, Room Temperature, 60 Hz.



### 9.5 Regulation

#### 9.5.1 Load and Line

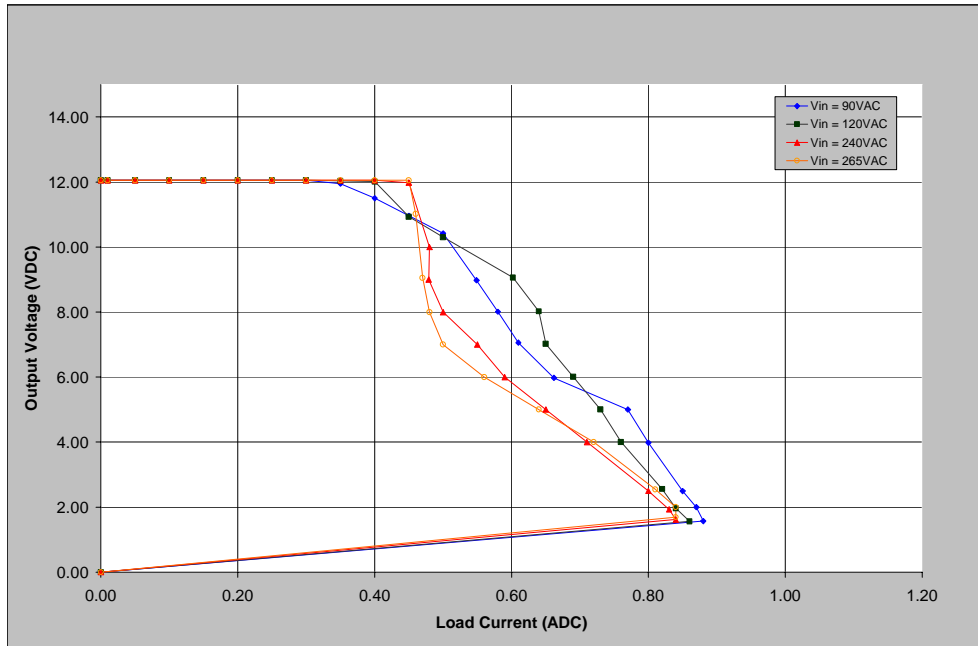


Figure 10 – Load Regulation, Room Temperature.

#### 9.5.2 Battery Load Charge Profile at 120VAC Input

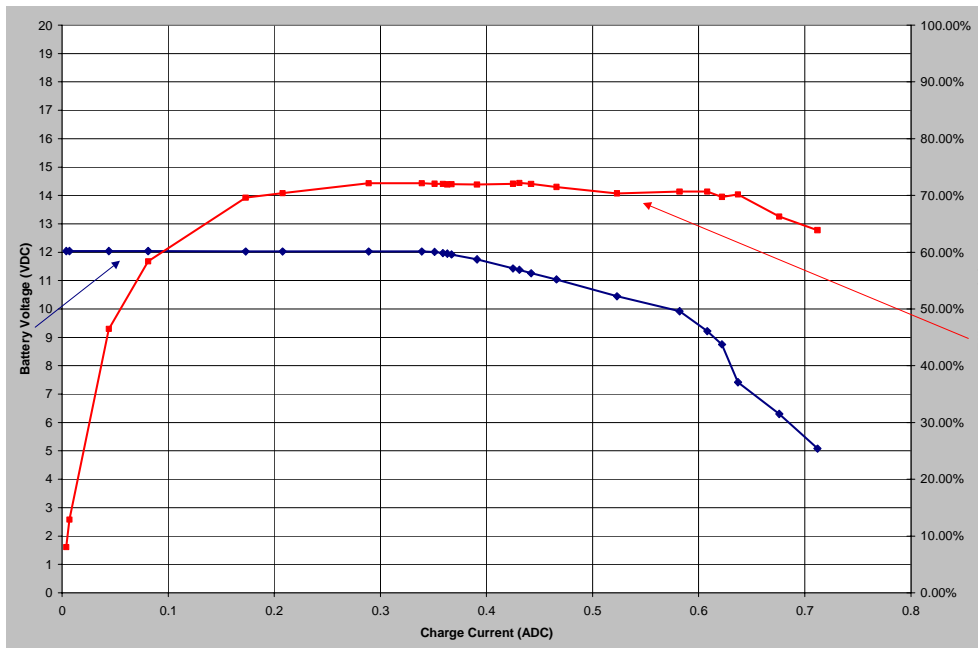


Figure 11 – Battery Charge Profile, Room Temperature.



## 10 Waveforms

### 10.1 Drain Voltage and Current, Normal Operation

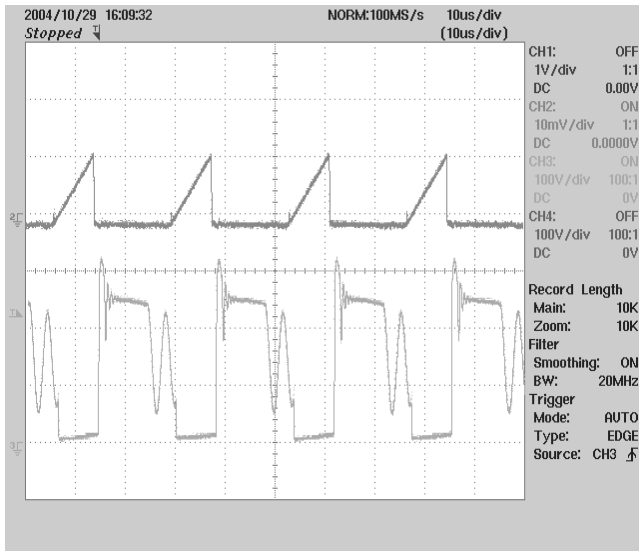


Figure 12 – 85VAC, Full Load

Upper:  $I_{DRAIN}$ , 0.2 A / div  
Lower:  $V_{DRAIN}$ , 100 V, 10  $\mu$ s / div

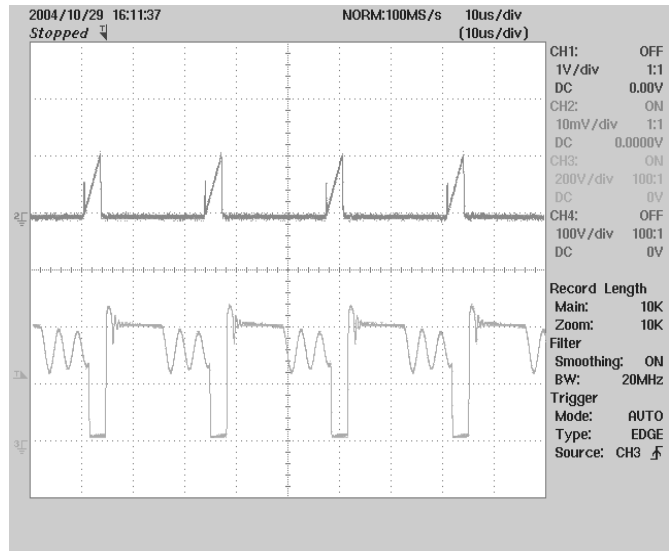


Figure 13 – 265VAC, Full Load

Upper:  $I_{DRAIN}$ , 0.2 A / div  
Lower:  $V_{DRAIN}$ , 200 V / div

### 10.2 Output Voltage Start-up Profile

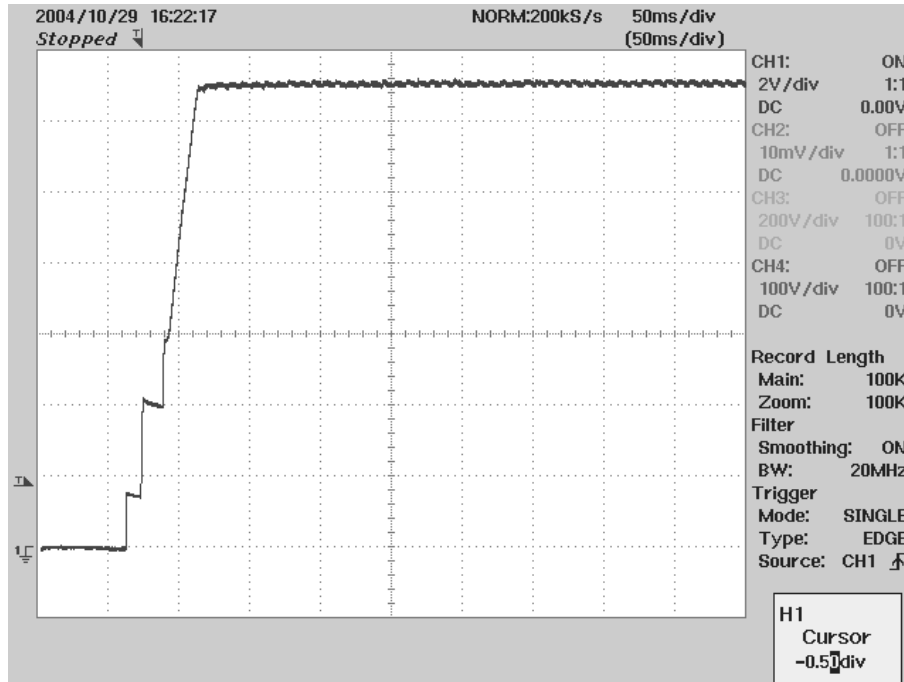


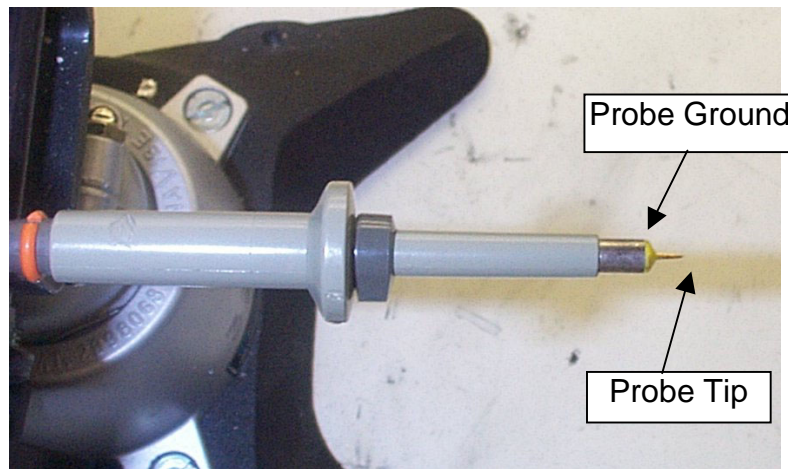
Figure 14 – Start-up Profile  $V_{in}$  = 115VAC; 12V @ 400mA, 2 V, 50 ms / div.

### 10.3 Output Ripple Measurements

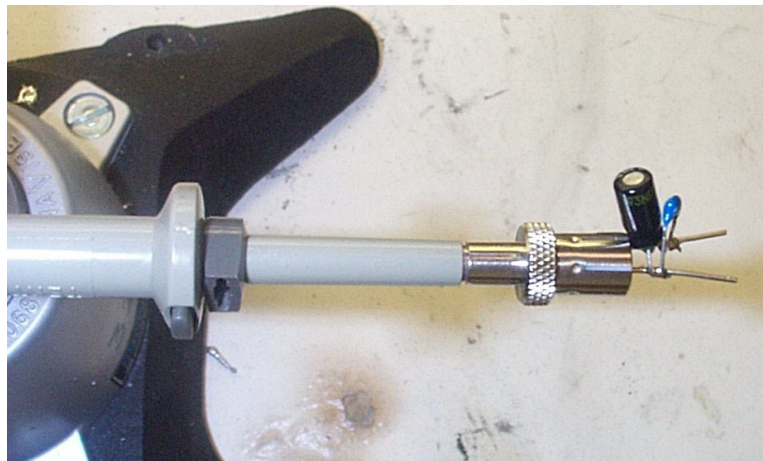
#### 10.3.1 Ripple Measurement Technique

For DC output ripple measurements, a modified oscilloscope test probe must be utilized in order to reduce spurious signals due to pickup. Details of the probe modification are provided in Figure 15 and Figure 16.

The 5125BA probe adapter is affixed with two capacitors tied in parallel across the probe tip. The capacitors include one (1) 0.1  $\mu\text{F}/50\text{ V}$  ceramic type and one (1) 1.0  $\mu\text{F}/50\text{ V}$  aluminum electrolytic. **The aluminum electrolytic type capacitor is polarized, so proper polarity across DC outputs must be maintained (see below).**



**Figure 15** – Oscilloscope Probe Prepared for Ripple Measurement. (End Cap and Ground Lead Removed)



**Figure 16** – Oscilloscope Probe with Probe Master 5125BA BNC Adapter. (Modified with wires for probe ground for ripple measurement, and two parallel decoupling capacitors added)

10.3.2 Measurement Results

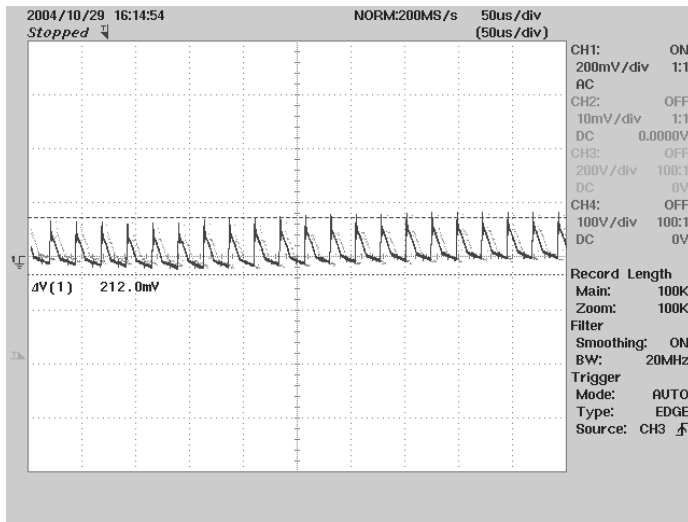


Figure 17 – Ripple, 120VAC, Full Load.  
50  $\mu$ s, 200 mV / div

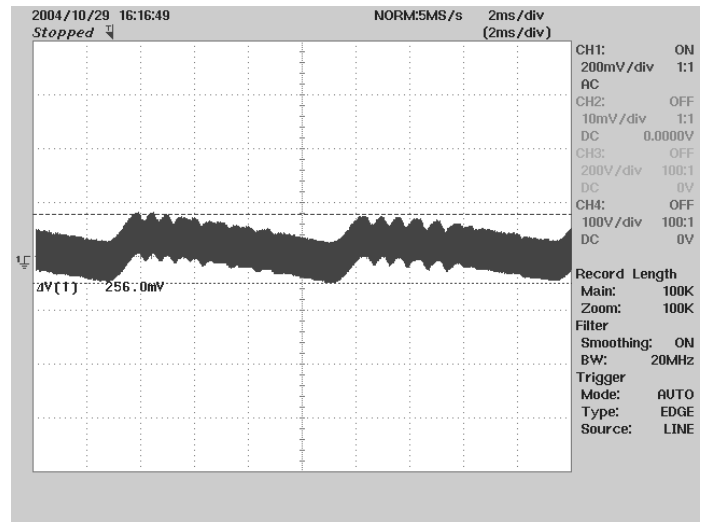


Figure 18 – Ripple, 120VAC, Full Load.  
2 ms, 200 mV / div



## 11 Conducted EMI

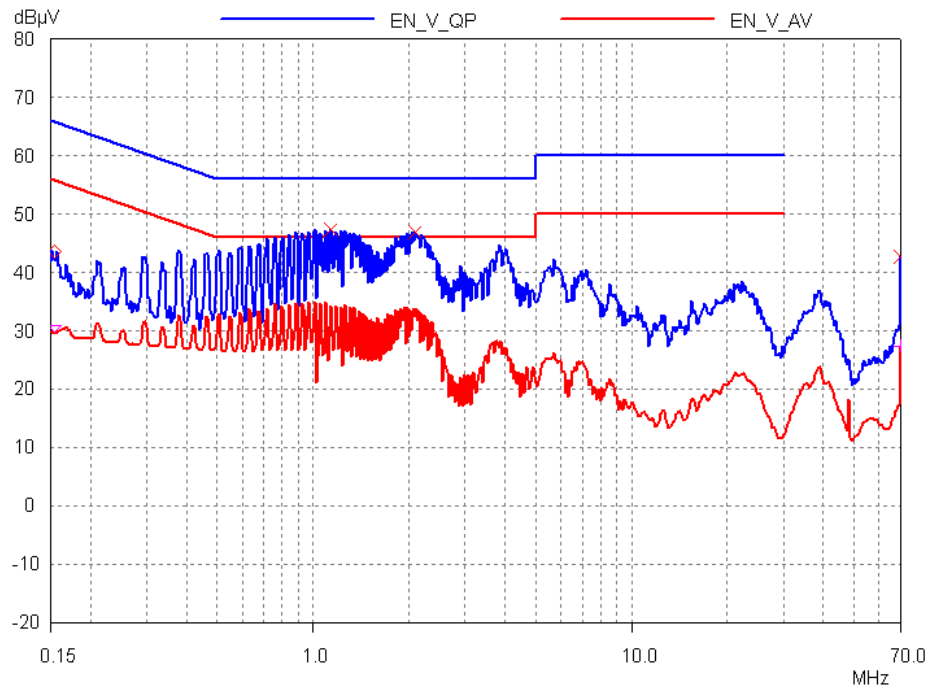


Figure 19 – Conducted EMI, Maximum Steady State Load, 115VAC, 60 Hz, and EN55022 B Limits

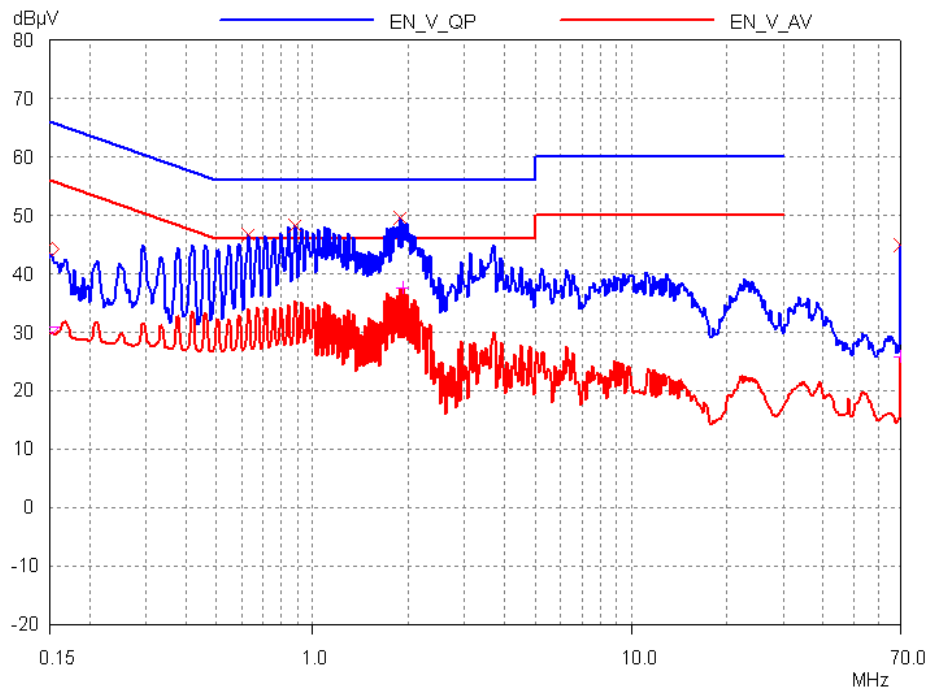


Figure 20 – Conducted EMI, Maximum Steady State Load, 230VAC, 60 Hz, and EN55022 B Limits



## 12 Revision History

<b>Date</b>	<b>Author</b>	<b>Revision</b>	<b>Description &amp; changes</b>	<b>Reviewed</b>
April 20, 2005	RSP/EC	1.0	Initial release	KM / JC / AM



For the latest updates, visit our Web site: [www.powerint.com](http://www.powerint.com)

Power Integrations may make changes to its products at any time. Power Integrations has no liability arising from your use of any information, device or circuit described herein nor does it convey any license under its patent rights or the rights of others. POWER INTEGRATIONS MAKES NO WARRANTIES HEREIN AND SPECIFICALLY DISCLAIMS ALL WARRANTIES INCLUDING, WITHOUT LIMITATION, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND NON-INFRINGEMENT OF THIRD PARTY RIGHTS.

#### PATENT INFORMATION

The products and applications illustrated herein (including circuits external to the products and transformer construction) may be covered by one or more U.S. and foreign patents or potentially by pending U.S. and foreign patent applications assigned to Power Integrations. A complete list of Power Integrations' patents may be found at [www.powerint.com](http://www.powerint.com).

The PI Logo, **TOPSwitch**, **TinySwitch**, **LinkSwitch**, and **EcoSmart** are registered trademarks of Power Integrations. **PI Expert** and **DPA-Switch** are trademarks of Power Integrations.

© Copyright 2004, Power Integrations.

### Power Integrations Worldwide Sales Support Locations

#### WORLD HEADQUARTERS

5245 Hellyer Avenue,  
San Jose, CA 95138, USA  
Main: +1-408-414-9200  
Customer Service:  
Phone: +1-408-414-9665  
Fax: +1-408-414-9765  
e-mail:  
[usasales@powerint.com](mailto:usasales@powerint.com)

#### CHINA (SHANGHAI)

Rm 807, Pacheer,  
Commercial Centre,  
555 Nanjing West Road,  
Shanghai, 200041, China  
Phone: +86-21-6215-5548  
Fax: +86-21-6215-2468  
e-mail:  
[chinasales@powerint.com](mailto:chinasales@powerint.com)

#### CHINA (SHENZHEN)

Rm# 1705, Bao Hua Bldg.  
1016 Hua Qiang Bei Lu,  
Shenzhen, Guangdong,  
518031, China  
Phone: +86-755-8367-5143  
Fax: +86-755-8377-9610  
e-mail:  
[chinasales@powerint.com](mailto:chinasales@powerint.com)

#### APPLICATIONS HOTLINE

World Wide +1-408-414-9660

#### GERMANY

Rueckertstrasse 3,  
D-80336, Munich, Germany  
Phone: +49-895-527-3910  
Fax: +49-895-527-3920  
e-mail: [eurosales@powerint.com](mailto:eurosales@powerint.com)

#### INDIA (TECHNICAL SUPPORT)

Innovatech  
261/A, Ground Floor  
7th Main, 17th Cross,  
Sadashivanagar  
Bangalore, India, 560080  
Phone: +91-80-5113-8020  
Fax: +91-80-5113-8023  
e-mail: [indiasales@powerint.com](mailto:indiasales@powerint.com)

#### ITALY

Via Vittorio Veneto 12, Bresso,  
Milano,  
20091, Italy  
Phone: +39-028-928-6001  
Fax: +39-028-928-6009  
e-mail: [eurosales@powerint.com](mailto:eurosales@powerint.com)

#### APPLICATIONS FAX

World Wide +1-408-414-9760

#### JAPAN

Keihin-Tatemono 1st Bldg.  
12-20 Shin-Yokohama,  
2-Chome,  
Kohoku-ku, Yokohama-shi,  
Kanagawa 222-0033, Japan  
Phone: +81-45-471-1021  
Fax: +81-45-471-3717  
e-mail:  
[japansales@powerint.com](mailto:japansales@powerint.com)

#### KOREA

8th Floor, DongSung Bldg.  
17-8 Yoido-dong,  
Youngdeungpo-gu,  
Seoul, 150-874, Korea  
Phone: +82-2-782-2840  
Fax: +82-2-782-4427  
e-mail:  
[koreasales@powerint.com](mailto:koreasales@powerint.com)

#### SINGAPORE

51 Newton Road,  
#15-08/10 Goldhill Plaza,  
Singapore, 308900  
Phone: +65-6358-2160  
Fax: +65-6358-2015  
e-mail:  
[singaporesales@powerint.com](mailto:singaporesales@powerint.com)

#### TAIWAN

17F-3, No. 510,  
Chung Hsiao E. Rd., Sec. 5,  
Taipei, Taiwan 110, R.O.C.  
Phone: +886-2-2727-1221  
Fax: +886-2-2727-1223  
e-mail:  
[taiwansales@powerint.com](mailto:taiwansales@powerint.com)

#### UK (EUROPE & AFRICA HEADQUARTERS)

1st Floor, St. James's House  
East Street  
Farnham, Surrey GU9 7TJ  
United Kingdom  
Phone: +44-1252-730-140  
Fax: +44-1252-727-689  
e-mail: [eurosales@powerint.com](mailto:eurosales@powerint.com)

